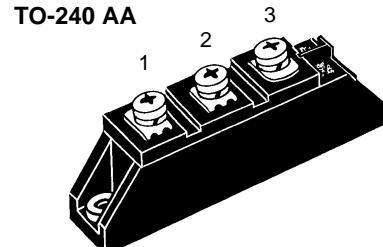
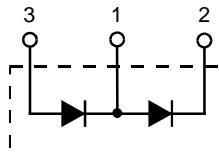


Diode Modules

I_{FRMS} = 2x 150 A
I_{FAVM} = 2x 95 A
V_{RRM} = 800-1800 V

V _{RSM} V	V _{RRM} V	Type
900	800	MDD 56-08N1 B
1300	1200	MDD 56-12N1 B
1500	1400	MDD 56-14N1 B
1700	1600	MDD 56-16N1 B
1900	1800	MDD 56-18N1 B



Symbol	Test Conditions	Maximum Ratings	
I _{FRMS}	T _{VJ} = T _{VJM}	150	A
I _{FAVM}	T _C = 75°C; 180° sine	95	A
	T _C = 100°C; 180° sine	71	A
I _{FSM}	T _{VJ} = 45°C; V _R = 0	1400 t = 10 ms (50 Hz), sine 1650 t = 8.3 ms (60 Hz), sine	A A
	T _{VJ} = T _{VJM} V _R = 0	1200 t = 10 ms (50 Hz), sine 1400 t = 8.3 ms (60 Hz), sine	A A
j ² dt	T _{VJ} = 45°C V _R = 0	9800 t = 10 ms (50 Hz), sine 11300 t = 8.3 ms (60 Hz), sine	A ² s A ² s
	T _{VJ} = T _{VJM} V _R = 0	7200 t = 10 ms (50 Hz), sine 8100 t = 8.3 ms (60 Hz), sine	A ² s A ² s
T _{VJ}		-40...+150	°C
T _{VJM}		150	°C
T _{stg}		-40...+125	°C
V _{ISOL}	50/60 Hz, RMS I _{ISOL} ≤ 1 mA	3000 t = 1 min 3600 t = 1 s	V~ V~
M _d	Mounting torque (M5) Terminal connection torque (M5)	2.5-4/22-35 Nm/lb.in. 2.5-4/22-35 Nm/lb.in.	
Weight	Typical including screws	90	g
Symbol	Test Conditions	Characteristic Values	
I _R	T _{VJ} = T _{VJM} ; V _R = V _{RRM}	10	mA
V _F	I _F = 200 A; T _{VJ} = 25°C	1.48	V
V _{TO}	For power-loss calculations only	0.8	V
r _T	T _{VJ} = T _{VJM}	3	mΩ
Q _S	T _{VJ} = 125°C; I _F = 50 A, -di/dt = 3 A/μs	100	μC
I _{RM}		24	A
R _{thJC}	per diode; DC current	0.51	K/W
	per module	0.255	K/W
R _{thJK}	per diode; DC current	0.71	K/W
	per module	0.355	K/W
d _s	Creepage distance on surface	12.7	mm
d _A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
 IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al₂O₃ -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

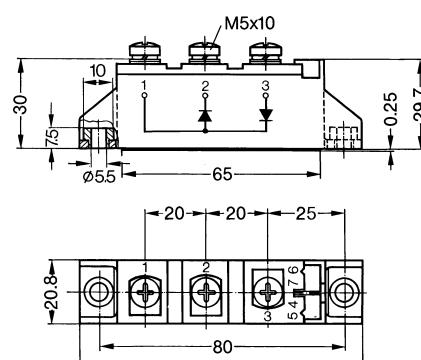
Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



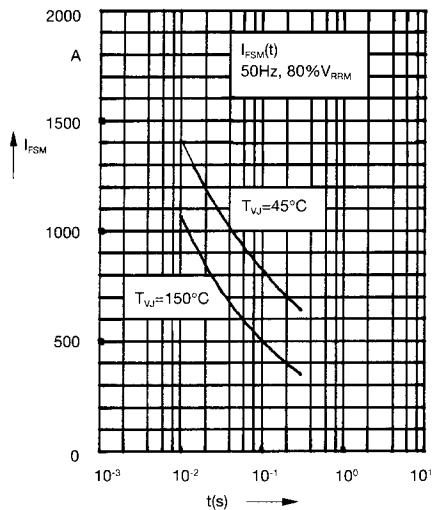


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t : duration

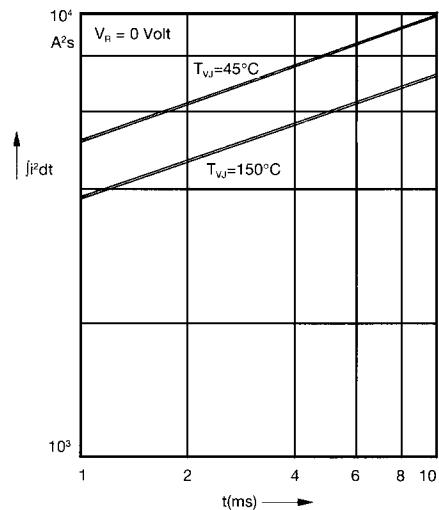


Fig. 2 $\int j^2 dt$ versus time (1-10 ms)

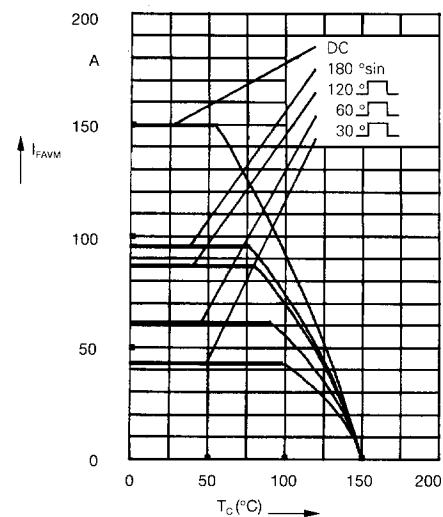


Fig. 2a Maximum forward current
at case temperature

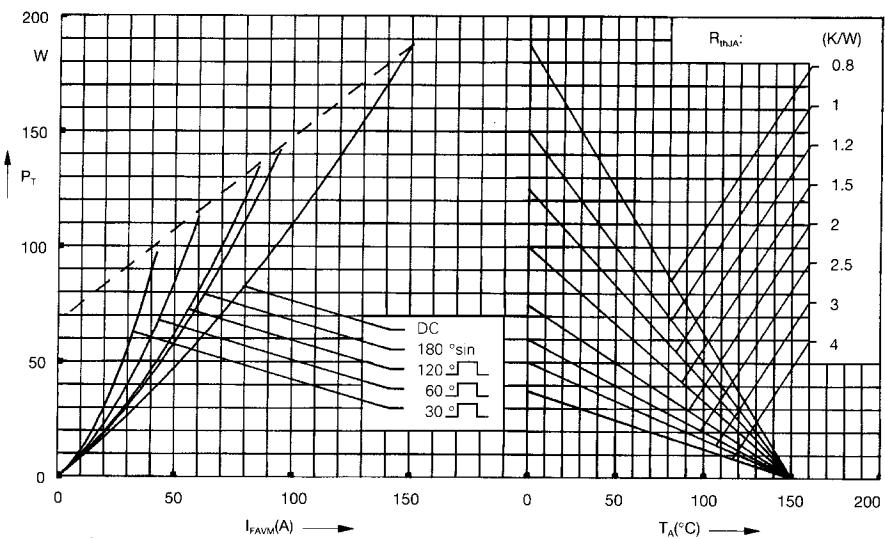


Fig. 3 Power dissipation versus
forward current and ambient
temperature (per diode)

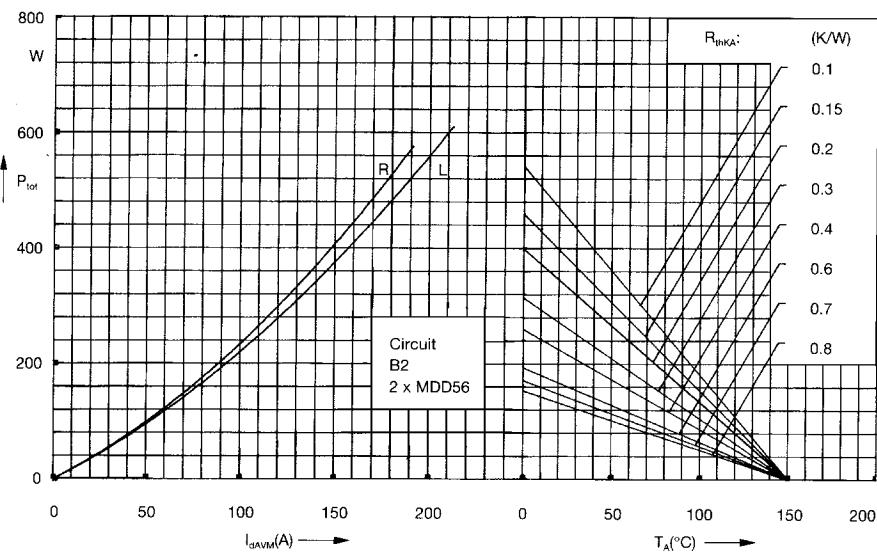


Fig. 4 Single phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature
R = resistive load
L = inductive load

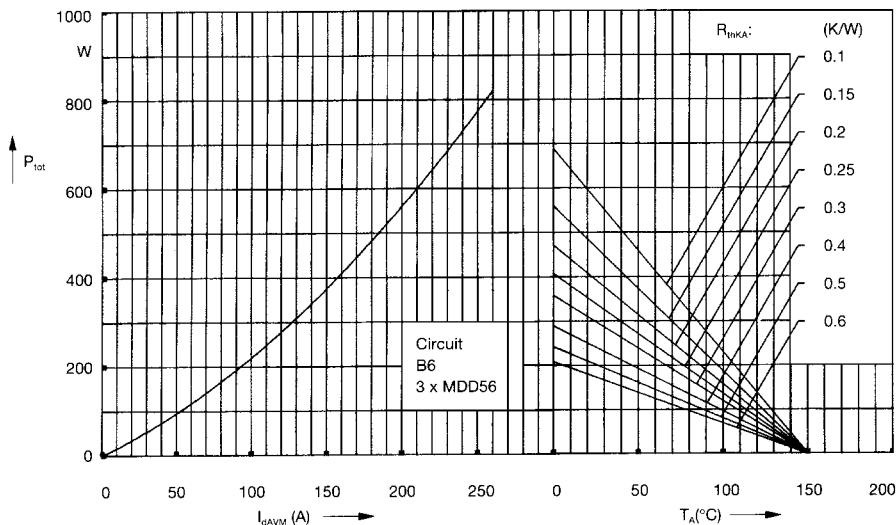


Fig. 5 Three phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature

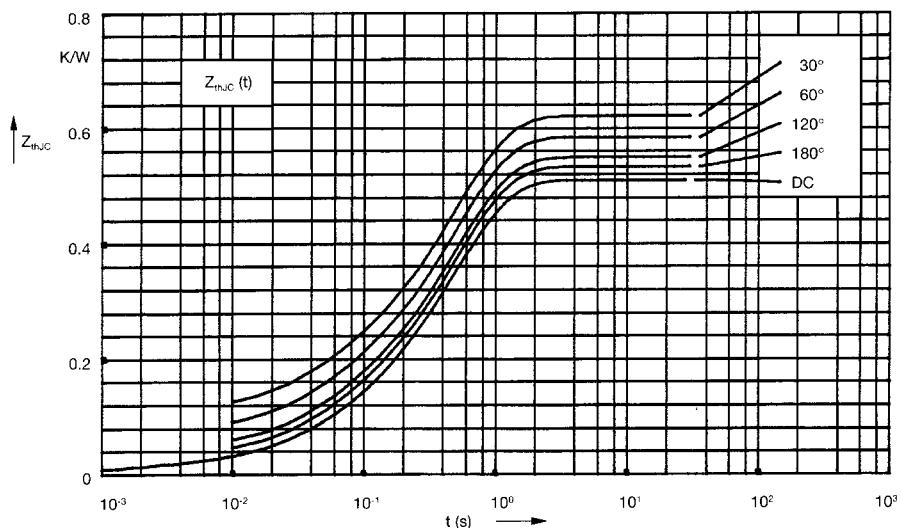


Fig. 6 Transient thermal impedance
junction to case (per diode)

d	R_{thJC} (K/W)
DC	0.51
180°	0.53
120°	0.55
60°	0.58
30°	0.62

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.013	0.0015
2	0.055	0.045
3	0.442	0.485

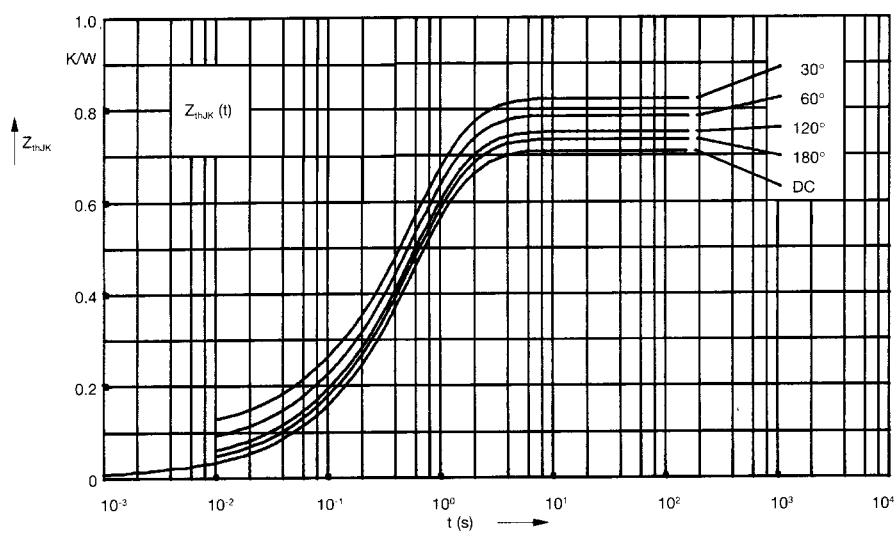


Fig. 7 Transient thermal impedance
junction to heatsink (per diode)

d	R_{thJK} (K/W)
DC	0.71
180°	0.73
120°	0.75
60°	0.78
30°	0.82

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.013	0.0015
2	0.055	0.045
3	0.442	0.485
4	0.2	1.25